Venue

The Conference will be held in the Hotel "Holiday Inn St.Petersburg" located on a straight way from Pulkovo Airport (25 min) to St. Petersburg downtown (15 min).

Hotel «Holiday Inn St. Petersburg» offers:

- Congress hall for 450 people, provided with necessary modern equipment
- Spacious foyers around the hall for poster sessions, coffee-breaks, and exhibition
- Several restaurants to organize welcome reception and lunches for 250 persons simultaneously
- Wi-Fi Internet connection for the symposium participants in public places

Accommodation

Hotel «Holiday Inn St.Petersburg» will provide ~50 comfortable rooms with a conference discount (rates 110-120 EUR per night) for Workshop participants.

Participants who would like to stay in the hotel "Holiday Inn St. Petersburg" are to complete an Accommodation Form, which will be available on June 1, 2019, at the Workshop website. The Accommodation Forms will be collected and processed by the Organizing Committee with the preference to early booking.

Participants can also book different hotels in the very downtown for 50-100 EUR per night. It takes 15 min max by subway to get to the Workshop venue.

Please send correspondence to the Secretary
Dr. Tatiana Komissarova, Ioffe Institute
Polytekhnicheskaya 26, St.Petersburg 194021, Russia.
Fax: +7 (812) 297-1017, Phone: +7 (812) 292-7124
e-mail: iwumd4@mail.ioffe.ru & iwumd4@gmail.ru

Registration fee

	Early registration, EUR, before 30.06.2019	Late registration, EUR, after 30.06.2019
Regular participants	550	650
Student participants	350	400
Accompanying persons	270	350

Registration Fee covers admission to all Workshop sessions, a Workshop program and abstracts booklet, Welcome party (Monday, September 9), Workshop dinner (Thursday, September 12), coffee breaks, lunches, poster refreshments, sightseeing tour (Thursday, September 12), and visa support.

Registration Fee for accompanying persons covers Welcome party, lunches, Workshop dinner, coffee breaks, sightseeing tour, and visa support.

Exhibition

Exhibition of products and services related to UV materials, devices, and technologies will be held as an integral part of the Workshop. The detailed information on exhibitor's registration and conditions is available at the Workshop website.

Visa support

Participants who need a visa to enter Russian Federation are to complete the relevant fields in the Visa Form, which will be available from June 1, 2019, and send it with a scanned copy of the passport page with a photo to Organizing Committee by e-mail. After submission of the Visa Form the official Invitation letter from Ioffe Institute or from the Ministry of Foreign Affairs depending on the participant citizenship will be sent to the participants for application for the Russian humanitarian visa.

Important dates

Abstract submission deadline (extended)	May 20, 2019
Notification of abstract acceptance	June 10, 2019
Deadline for post-deadline abstract submission	June 30, 2019

www.ioffe.ru/IWUMD4

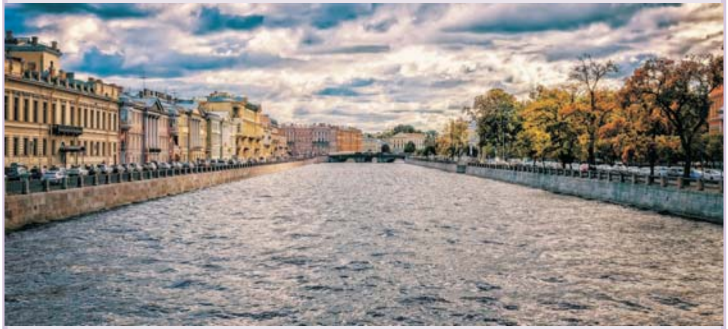
4th International Workshop on Ultraviolet Materials and Devices

IWUMD IV

September 8-13, 2019,
Saint Petersburg, Russia

Workshop Chair
Sergey Ivanov, Ioffe Institute, Russia

Ioffe Institute



Second announcement
Call for abstracts

www.ioffe.ru/IWUMD4

The 4th International Workshop on Ultraviolet (UV) Materials and Devices (IWUMD4) is organized by Ioffe Insitute (St.Petersburg, Russia) and continues a series of the successful meetings of UV community, held in Beijing, China (2016), Fukuoka, Japan (2017), Kunming, China (2018). The workshop gets together prominent and young scientists in warm and friendly atmosphere. It provides a unique opportunity for the presentation and open discussion of latest results on R&D of novel UV materials and devices, new trends in basic and applied studies, modelling, and innovative technologies.

Main scientific topics:

- AlN bulk crystals and templates
- Growth and properties of AlGaN heterostructures
- BN growth and fundamental properties
- Oxides (Ga_2O_3 etc.) growth and fundamental properties
- Wide-gap heterostructure physics
- Nanostructures and nanodevices
- UV photonic AlGaN devices
- Non-AlGaN UV photonic devices

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at Ioffe Institute

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Tatiana Komissarova - Secretary
Irina Sedova, Anton Lebedev,
E. Moltchanova, J. Senchenok

Abstract submission

Abstract Deadline (extended) is **May 20, 2019.**
For details please visit the website:
http://www.ioffe.ru/IWUMD4

E-mail: iwumd4@mail.ioffe.ru
iwumd4@gmail.com

Plenary Speakers

Michael Kneissl, TU Berlin, Germany
Chris Van de Walle, UCSB, USA

Keynote Speakers

Guillaume Cassabois, Montpellier University, France
Hideki Hirayama, RIKEN, Japan
James Speck, UCSB, USA
Alexey Toropov, Ioffe Institute, Russia

Invited Speakers

Masayoshi Adachi, Tohoku University, Japan
Shigefusa Chichibu, Tohoku University, Japan
Juergen Christen, Magdeburg University, Germany
Bruno Daudin, CEA-Granoble, France
Sven Einfeldt, Ferdinand-Braun-Institut, Germany
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Akira Hirano, UV Craftory Co. Nagoya, Japan
Axel Hoffmann, TU Berlin, Germany
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